

# PJA3413-AU

## 20V P-Channel Enhancement Mode MOSFET

Voltage

-20 V

Current

-3.4A

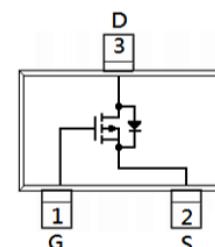
### Features

- $R_{DS(ON)}$ ,  $V_{GS} @ -4.5V$ ,  $I_D @ -3.4A < 82m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS} @ -2.5V$ ,  $I_D @ -2.2A < 110m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS} @ -1.8V$ ,  $I_D @ -1.2A < 146m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0084 grams

SOT-23



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ C$ unless otherwise noted)

| PARAMETER   | SYMBOL                    | LIMIT    | UNITS                 |
|---|---------------------------|----------|-----------------------|
| Drain-Source Voltage  | $V_{DS}$                  | -20      | V                     |
| Gate-Source Voltage   | $V_{GS}$                  | $\pm 12$ |                       |
| Continuous Drain Current <sup>(Note 4)</sup>                              | $I_D$                     | -3.4     | A                     |
| Pulsed Drain Current <sup>(Note 1)</sup>                                  | $I_{DM}$                  | -13.6    |                       |
| Power Dissipation   | $T_a=25^\circ C$          | 1.25     | W                     |
|   | Derate above $25^\circ C$ | 10       | $mW/\text{ }^\circ C$ |
| Operating Junction and Storage Temperature Range                          | $T_J, T_{STG}$            | -55~150  | $^\circ C$            |
| Typical Thermal Resistance<br>- Junction to Ambient <sup>(Note 3,4)</sup> | $R_{\theta JA}$           | 100      | $^\circ C/W$          |

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### Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   | SYMBOL                     | TEST CONDITION   | MIN. | TYP.  | MAX.      | UNITS            |
|---|----------------------------|--|------|-------|-----------|------------------|
| <b>Static</b>   |                            |  |      |       |           |                  |
| Drain-Source Breakdown Voltage                        | $\text{BV}_{\text{DSS}}$   | $V_{\text{GS}}=0\text{V}, I_{\text{D}}=-250\mu\text{A}$  | -20  | -     | -         | V                |
| Gate Threshold Voltage                                | $V_{\text{GS}(\text{th})}$ | $V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=-250\mu\text{A}$  | -0.4 | -0.65 | -1.2      |                  |
| Drain-Source On-State Resistance                      | $R_{\text{DS}(\text{on})}$ | $V_{\text{GS}}=-4.5\text{V}, I_{\text{D}}=-3.4\text{A}$  | -    | 65    | 82        | $\text{m}\Omega$ |
|   |                            | $V_{\text{GS}}=-2.5\text{V}, I_{\text{D}}=-2.2\text{A}$  | -    | 82    | 110       |                  |
|   |                            | $V_{\text{GS}}=-1.8\text{V}, I_{\text{D}}=-1.2\text{A}$  | -    | 103   | 146       |                  |
| Zero Gate Voltage Drain Current                       | $I_{\text{DSS}}$           | $V_{\text{DS}}=-20\text{V}, V_{\text{GS}}=0\text{V}$   | -    | -     | -1        | $\mu\text{A}$    |
| Gate-Source Leakage Current                           | $I_{\text{GSS}}$           | $V_{\text{GS}}=\pm 12\text{V}, V_{\text{DS}}=0\text{V}$  | -    | -     | $\pm 100$ | nA               |
| <b>Dynamic</b> <sup>(Note 5)</sup>                    |                            |  |      |       |           |                  |
| Total Gate Charge                                     | $Q_g$                      | $V_{\text{DS}}=-10\text{V}, I_{\text{D}}=-3.4\text{A}, V_{\text{GS}}=-4.5\text{V}^{(\text{Note 1,2})}$                       | -    | 7     | -         | nC               |
| Gate-Source Charge                                    | $Q_{\text{gs}}$            |  | -    | 1     | -         |                  |
| Gate-Drain Charge                                     | $Q_{\text{gd}}$            |  | -    | 1.8   | -         |                  |
| Input Capacitance                                     | $C_{\text{iss}}$           | $V_{\text{DS}}=-10\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHZ}$  | -    | 522   | -         | pF               |
| Output Capacitance                                    | $C_{\text{oss}}$           |  | -    | 55    | -         |                  |
| Reverse Transfer Capacitance                          | $C_{\text{rss}}$           |  | -    | 40    | -         |                  |
| Turn-On Delay Time                                    | $t_{\text{d}(\text{on})}$  | $V_{\text{DD}}=-10\text{V}, I_{\text{D}}=-3.4\text{A}, V_{\text{GS}}=-4.5\text{V}, R_{\text{G}}=6\Omega^{(\text{Note 1,2})}$ | -    | 10    | -         | ns               |
| Turn-On Rise Time                                     | $t_{\text{r}}$             |  | -    | 4     | -         |                  |
| Turn-Off Delay Time                                   | $t_{\text{d}(\text{off})}$ |  | -    | 34    | -         |                  |
| Turn-Off Fall Time                                    | $t_{\text{f}}$             |  | -    | 5     | -         |                  |
| <b>Drain-Source Diode</b>                             |                            |  |      |       |           |                  |
| Maximum Continuous Drain-Source Diode Forward Current | $I_{\text{s}}$             | ---  | -    | -     | -1.5      | A                |
| Diode Forward Voltage                                 | $V_{\text{SD}}$            | $I_{\text{s}}=1\text{A}, V_{\text{GS}}=0\text{V}$  | -    | -0.77 | -1.2      | V                |

#### NOTES :

1. Pulse width  $\leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$ .
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\text{OJA}}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.

# PJA3413-AU

## TYPICAL CHARACTERISTIC CURVES

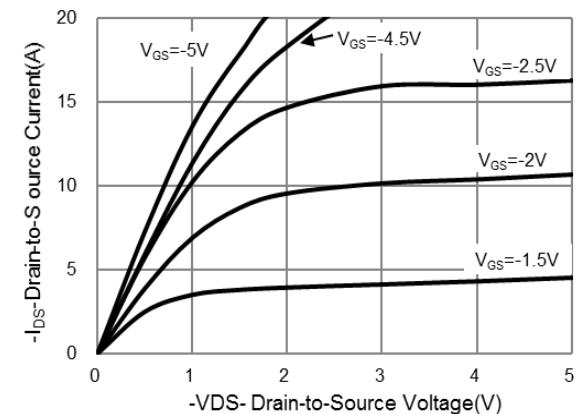


Fig.1 On-Region Characteristics

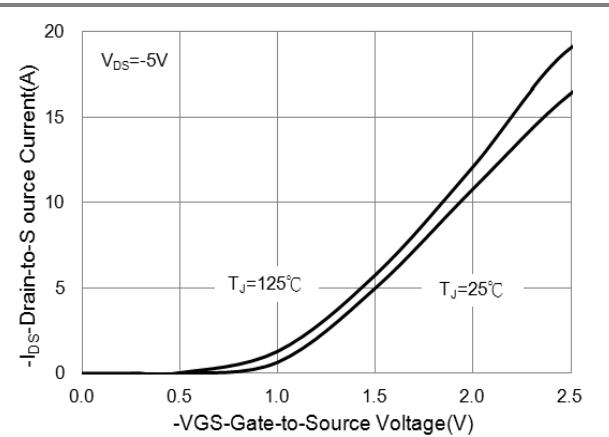


Fig.2 Transfer Characteristics

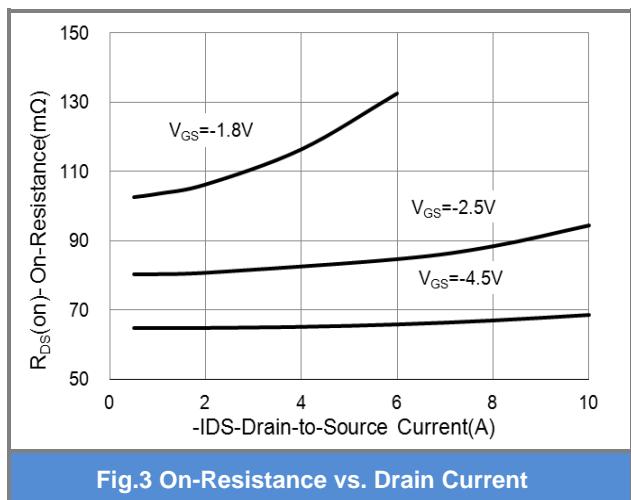


Fig.3 On-Resistance vs. Drain Current

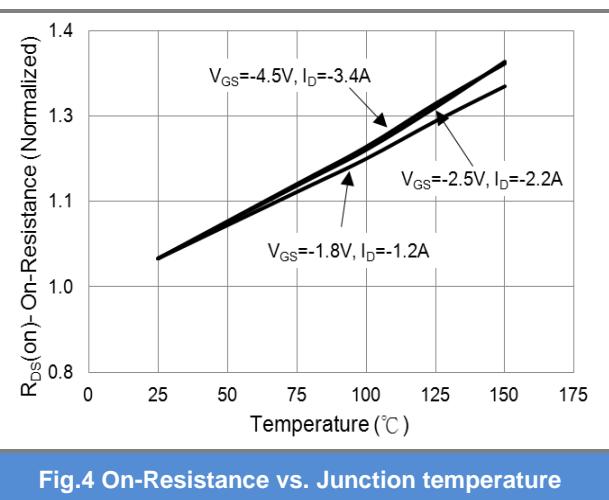


Fig.4 On-Resistance vs. Junction temperature

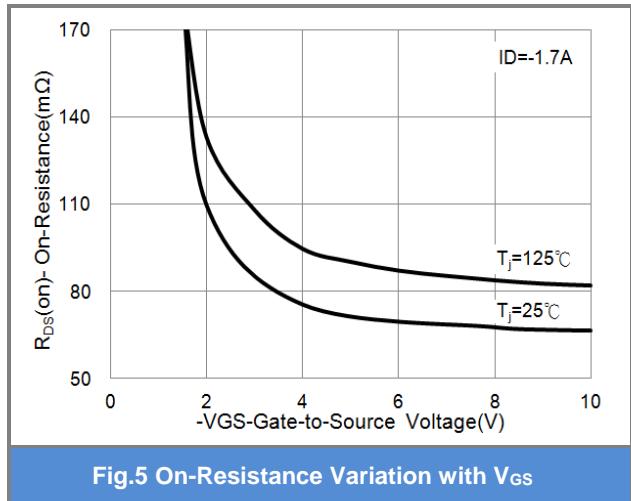


Fig.5 On-Resistance Variation with V<sub>GS</sub>

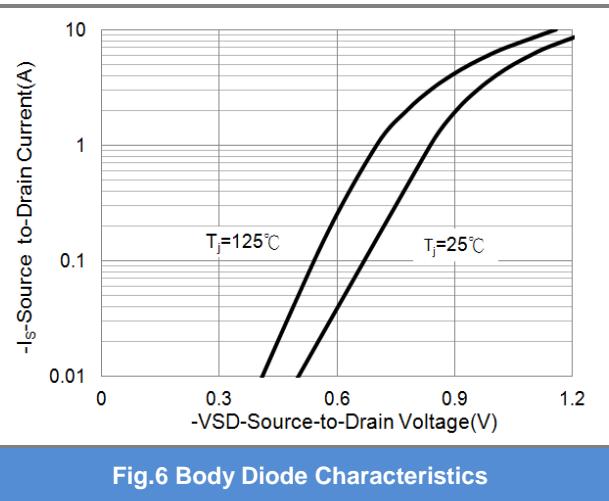


Fig.6 Body Diode Characteristics

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## TYPICAL CHARACTERISTIC CURVES

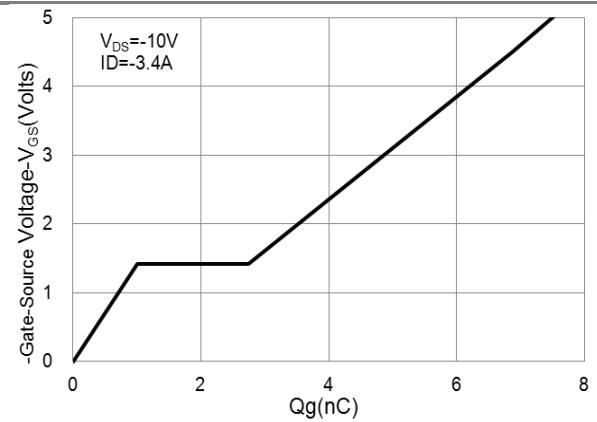


Fig.7 Gate-Charge Characteristics

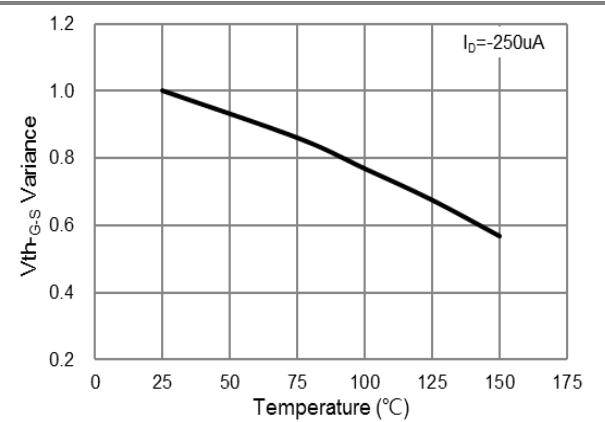


Fig.8 Threshold Voltage Variation with Temperature

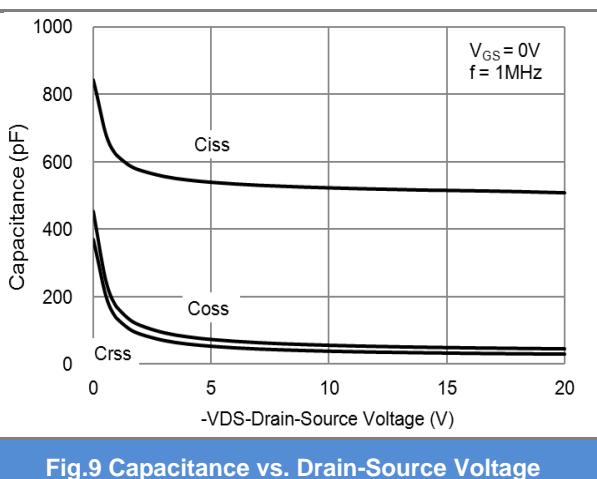


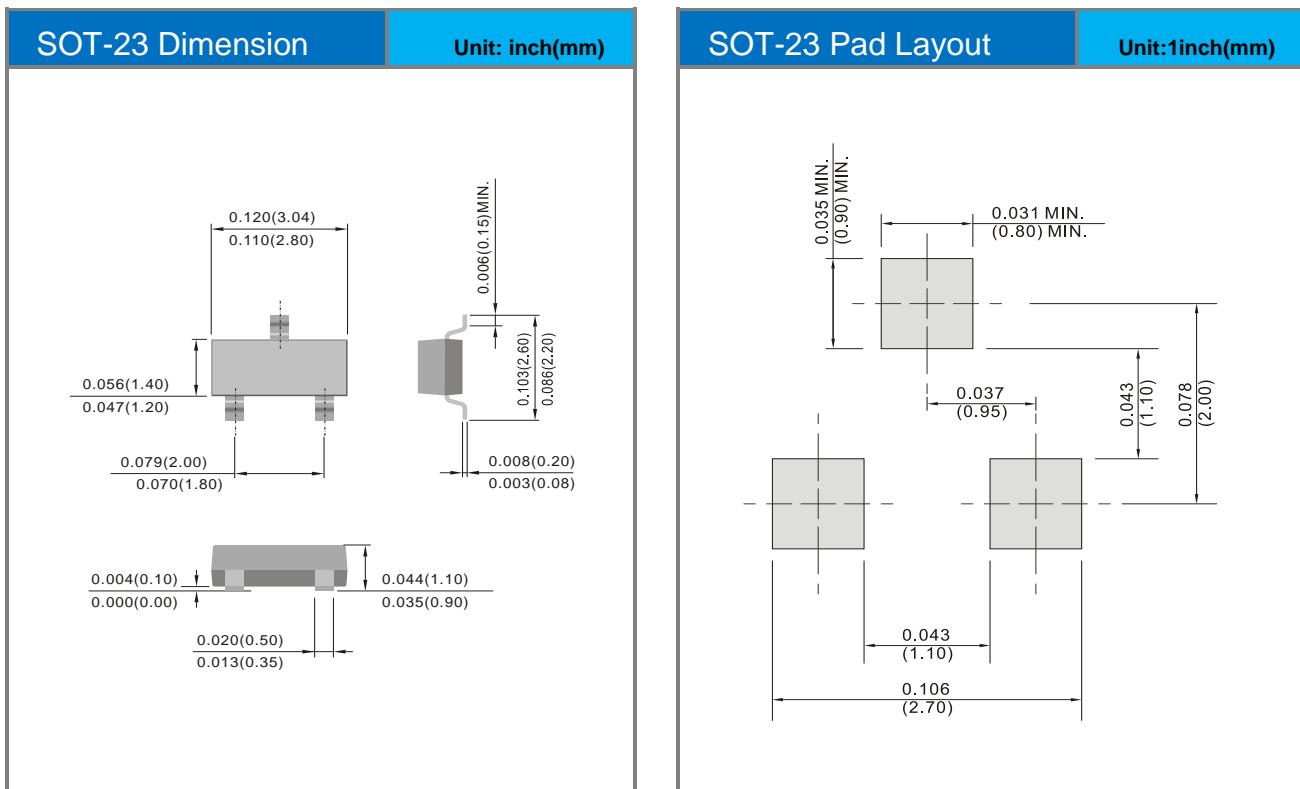
Fig.9 Capacitance vs. Drain-Source Voltage

## PJA3413-AU

### Product and Packing Information

| Part No.   | Package Type | Packing Type     | Marking |
|------------|--------------|------------------|---------|
| PJA3413-AU | SOT-23       | 3K pcs / 7" reel | A13     |

### Packaging Information & Mounting Pad Layout



## PJA3413-AU

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